# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

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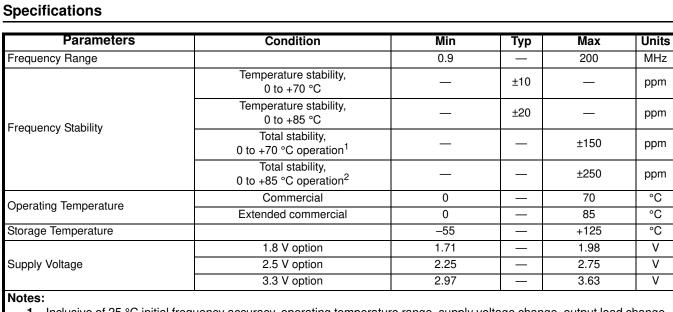




## DIFFERENTIAL OUTPUT SILICON OSCILLATOR

#### Features

- Quartz-free, MEMS-free, and PLL-free all-silicon oscillator
- Any output frequencies from 0.9 to 200 MHz
- Short lead times
- Excellent temperature stability (±20 ppm)
- Highly reliable startup and operation
  - High immunity to shock and vibration
- Low jitter: <1.5 ps rms
- 0 to 85 °C operation includes 10-year aging in hot environments
- Footprint compatible with industrystandard 3.2 x 5.0 mm XOs
- CMOS, SSTL, LVPECL, LVDS, and HCSL versions available
- Driver stopped, tri-state, or powerdown operation
- RoHS compliant
- 1.8, 2.5, or 3.3 V options
- Low power
- More than 10x better fit rate than competing crystal solutions



1. Inclusive of 25 °C initial frequency accuracy, operating temperature range, supply voltage change, output load change, first-year aging at 25 °C, shock, vibration, and one solder reflow.

2. Inclusive of 25 °C initial frequency accuracy, operating temperature range, supply voltage change, output load change, ten-year aging at 85 °C, shock, vibration, and one solder reflow.

**3.** See "AN409: Output Termination Options for the Si500S and Si500D Silicon Oscillators" for further details regarding output clock termination recommendations.

**4.**  $V_{TT} = .5 \times V_{DD}$ .

**5.**  $V_{TT} = .45 \times V_{DD}$ .

Parameters	Condition	Min	Тур	Max	Units
	LVPECL	_	34.0	36.0	mA
	Low Power LVPECL	_	19.3	22.2	mA
	LVDS		14.9	16.5	mA
	HCSL	_	25.3	29.3	mA
	Differential CMOS(3.3 V option, 10 pF on each output, 200 MHz)	_	33	36	mA
Supply Current	Differential CMOS(3.3 V option, 1 pFon each output, 40 MHz)	_	16	_	mA
	Differential SSTL-3.3		24.5	27.7	mA
	Differential SSTL-2.5	_	24.3	26.7	mA
	Differential SSTL-1.8	—	22.2	25	mA
	Tri-State	—	9.7	10.7	mA
	Powerdown		1.0	1.9	mA
Output Symmetry	$V_{DIFF} = 0$	46 – 13 ns/T <sub>CLK</sub>	—	54 + 13 ns/T <sub>CLK</sub>	%
	LVPECL/LVDS			460	ps
Rise and Fall Times (20/80%) <sup>3</sup>	HCSL/Differential SSTL			800	ps
	Differential CMOS, 15 pF, ≥80 MHz		1.1	1.6	ns
LVPECL Output Option	Mid-level	V <sub>DD</sub> – 1.5		V <sub>DD</sub> – 1.34	V
(DC coupling, 50 $\Omega$ to V <sub>DD</sub> – 2.0 V) <sup>3</sup>	Diff swing	.720	_	.880	V <sub>PK</sub>
Low Power LVPECL Output Option	Mid-level		N/A		V
(AC coupling, 100 $\Omega$ Differential Load) <sup>3</sup>	Diff swing	.68	_	.95	V <sub>PK</sub>
LVDS Output Option (2.5/3.3 V)	Mid-level	1.15		1.26	V
$(R_{TERM} = 100 \ \Omega \ diff)^3$	Diff swing	0.25		0.45	V <sub>PK</sub>
LVDS Output Option (1.8 V)	Mid-level	0.85	—	0.96	V
$(R_{\text{TERM}} = 100 \ \Omega \ \text{diff})^3$	Diff swing	0.25	—	0.45	V <sub>PK</sub>
	Mid-level	0.35	_	0.425	V
HCSL Output Option <sup>3</sup>	Diff swing	0.65	_	0.82	V <sub>PK</sub>
	DC termination per pad	45	_	55	Ω
<b>211</b> 22 <b>2 1 1 1 1 1 1 1 1 1 1</b>	V <sub>OH</sub> , sourcing 9 mA	V <sub>DD</sub> – 0.6	_	_	V
CMOS Output Voltage <sup>3</sup>	V <sub>OL</sub> , sinking 9 mA		_	0.6	V
	V <sub>OH</sub>	V <sub>TT</sub> + 0.375		_	
SSTL-1.8 Output Voltage <sup>4</sup>	V <sub>OL</sub>			V <sub>TT</sub> – 0.375	V
	V <sub>OH</sub>	V <sub>TT</sub> + 0.48	_		
SSTL-2.5 Output Voltage <sup>4</sup>	V <sub>OL</sub> – –		V <sub>TT</sub> – 0.48	V	
	V <sub>OH</sub>	V <sub>TT</sub> + 0.48	_		
SSTL-3.3 Output Voltage <sup>5</sup>	V <sub>OL</sub>			V <sub>TT</sub> – 0.48	V
Powerup Time	From time V <sub>DD</sub> crosses min spec supply	_		2	ms
OE Deassertion to Clk Stop				250 + 3 x T <sub>CLK</sub>	ns
Return from Output Driver Stopped Mode		_	-	250 + 3 x T <sub>CLK</sub>	ns
Return From Tri-State Time			<u> </u>	12 + 3 x T <sub>CLK</sub>	μs
Notos			1	=	P

Notes:

1. Inclusive of 25 °C initial frequency accuracy, operating temperature range, supply voltage change, output load change, first-year aging at 25 °C, shock, vibration, and one solder reflow.

2. Inclusive of 25 °C initial frequency accuracy, operating temperature range, supply voltage change, output load change, ten-year aging at 85 °C, shock, vibration, and one solder reflow.

**3.** See "AN409: Output Termination Options for the Si500S and Si500D Silicon Oscillators" for further details regarding output clock termination recommendations.

**4.**  $V_{TT} = .5 \times V_{DD}$ .

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Parameters	Parameters Condition			Max	Units
Return From Powerdown Time	vn Time		—	2	ms
Period Jitter (1-sigma)	Non-CMOS	_	1	2	ps RMS
r enoù onter (1-sigina)	CMOS, C <sub>L</sub> = 7 pF	_	1	3	ps RMS
Integrated Phase Jitter	1.0 MHz – min(20 MHz, 0.4 x F <sub>OUT</sub> ),non-CMOS	_	0.6	1	ps RMS
integrated i nase onter	1.0 MHz – min(20 MHz, 0.4 x F <sub>OUT</sub> ),CMOS format	_	0.7	1.5	ps RMS

Notes:

1. Inclusive of 25 °C initial frequency accuracy, operating temperature range, supply voltage change, output load change, first-year aging at 25 °C, shock, vibration, and one solder reflow.

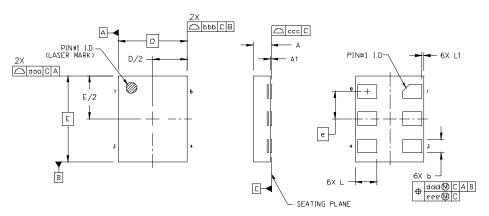
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3. See "AN409: Output Termination Options for the Si500S and Si500D Silicon Oscillators" for further details regarding output clock termination recommendations.

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#### **Package Specifications**

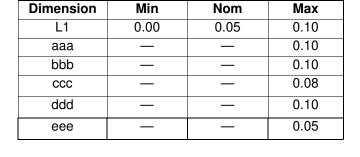


#### Table 1. Package Diagram Dimensions (mm)

Dimension	Min	Nom	Max
A	0.80	0.85	0.90
A1	0.00	0.03	0.05
b	0.59	0.64	0.69
D	3.20 BSC.		
е	1.27 BSC.		
E	4.00 BSC.		
L	0.95 1.00 1.05		1.05

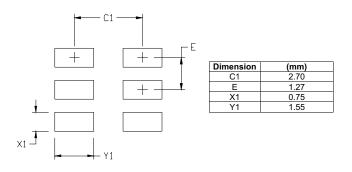
#### **Table 2. Pad Connections**

1	OE
2	NC—Make no external connection to this pin
3	GND
4	Output
5	Complementary Output
6	VDD

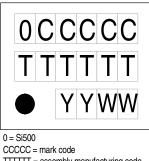


#### Table 3. Tri-State/Powerdown/Driver Stopped Function on OE (3rd Option Code)

	Α	В	С	D	Е	F
Open	Active	Active	Active	Active	Active	Active
1 Level	Active	Tri- State	Active	Power- down	Active	Driver Stopped
0 Level	Tri- State	Active	Power- down	Active	Driver Stopped	Active







TTTTTT = assembly manufacturing code YY = year WW = work week

#### Figure 2. Top Mark

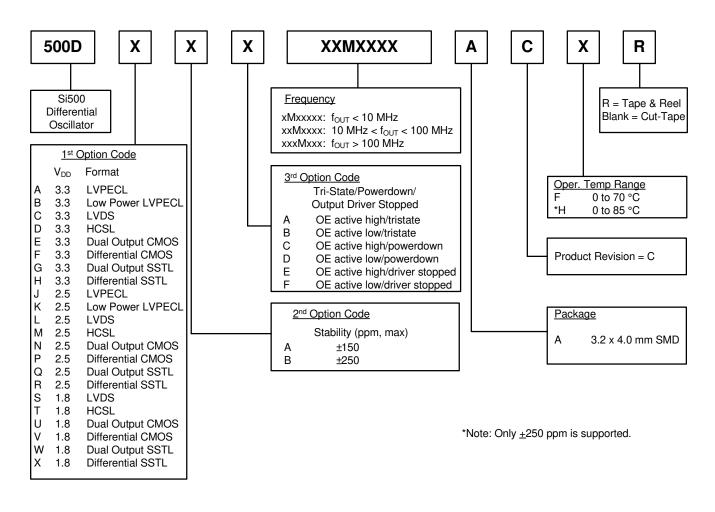


#### **Environmental Compliance**

Parameter	<b>Conditions/Test Method</b>		
Mechanical Shock	MIL-STD-883, Method 2002.4		
Mechanical Vibration	MIL-STD-883, Method 2007.3 A		
Resistance to Soldering Heat	MIL-STD-202, 260 C° for 8 seconds		
Solderability	MIL-STD-883, Method 2003.8		
Damp Heat	IEC 68-2-3		
Moisture Sensitivity Level	J-STD-020, MSL 3		

#### Ordering Information

The Si500D supports a variety of options including frequency, output format, supply voltage, and tristate/powerdown. Specific device configurations are programmed into the Si500D at time of shipment. Configurations are specified using the figure below. Silicon Labs provides a web-based part number utility that can be used to simplify part number configuration. Refer to www.silabs.com/SiliconXOPartnumber to access this tool. The Si500D XO series is supplied in a ROHS-compliant, Pb-free, 6-pad, 3.2 x 4.0 mm package. Tape and reel packaging is available as an ordering option.





### **DOCUMENT CHANGE LIST**

#### **Revision 0.2 to Revision 0.3**

- Revision B to Revision C updated in Ordering Information
- 0 to 85 C° Operating Temperature Range option added

#### **Revision 0.3 to Revision 1.0**

- Clarified SSTL specifications.
- Revised Differential CMOS supply current values.
- Clarified Differential CMOS supply current loading conditions.

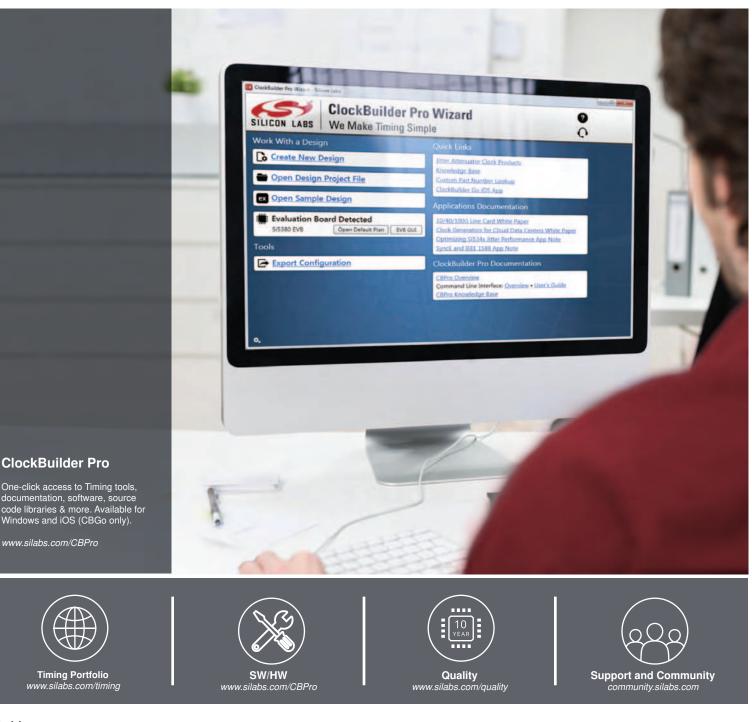
#### **Revision 1.0 to Revision 1.1**

- Updated Ordering information for ±250 ppm from 0 to +85 °C.
- Updated jitter from 1.5 ps to 1.5 ps rms.
- Updated operating temperature to include extended commercial at 0 to +85 °C.
- Updated features to include LVPECL, LVDS, and HCSL.



## NOTES:





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